NPN Triple Diffused Planar Silicon Transistor



# TT2138LS

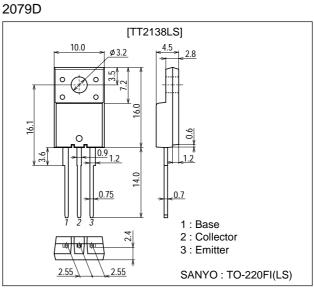
## Color TV Horizontal Deflection Output Applications

## Features

- High speed.
- High breakdown voltage (VCBO=1500V).
- High reliability (Adoption of HVP process).
- · Adoption of MBIT process.
- · On-chip damper diode.

## **Package Dimensions**

unit : mm



## **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

| Parameter                    | Symbol | Conditions | Ratings     | Unit |
|------------------------------|--------|------------|-------------|------|
| Collector-to-Base Voltage    | VCBO   |            | 1500        | V    |
| Collector-to-Emitter Voltage | VCEO   |            | 800         | V    |
| Emitter-to-Base Voltage      | VEBO   |            | 5           | V    |
| Collector Current            | IC     |            | 3.5         | А    |
| Collector Current (Pulse)    | ICP    |            | 9           | А    |
| Collector Dissipation        | PC     |            | 2.0         | W    |
|                              |        | Tc=25°C    | 25          | W    |
| Junction Temperature         | Tj     |            | 150         | °C   |
| Storage Temperature          | Tstg   |            | -55 to +150 | °C   |

#### Electrical Characteristics at Ta=25°C

| Parameter                 | Symbol    | Conditions                               | Ratings |     |     | Unit  |
|---------------------------|-----------|--|---------|-----|-----|-------|
|                           |           |  | min     | typ | max | Offic |
| Collector Cutoff Current  | ICBO      | V <sub>CB</sub> =800V, I <sub>E</sub> =0 |         |     | 10  | μΑ    |
| Collector Cutoff Current  | ICES      | VCE=1500V, RBE=0                         |         |     | 1.0 | mA    |
| Collector Sustain Voltage | VCEO(sus) | IC=100mA, IB=0                           | 800     |     |     | V     |
| Emitter Cutoff Current    | IEBO      | V <sub>EB</sub> =4V, I <sub>C</sub> =0   | 40      |     | 130 | mA    |

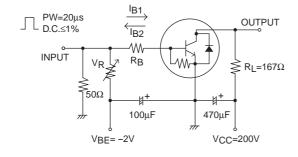
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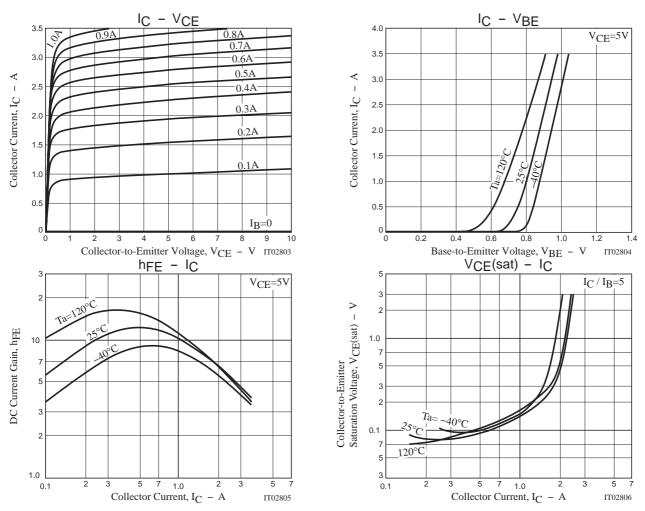
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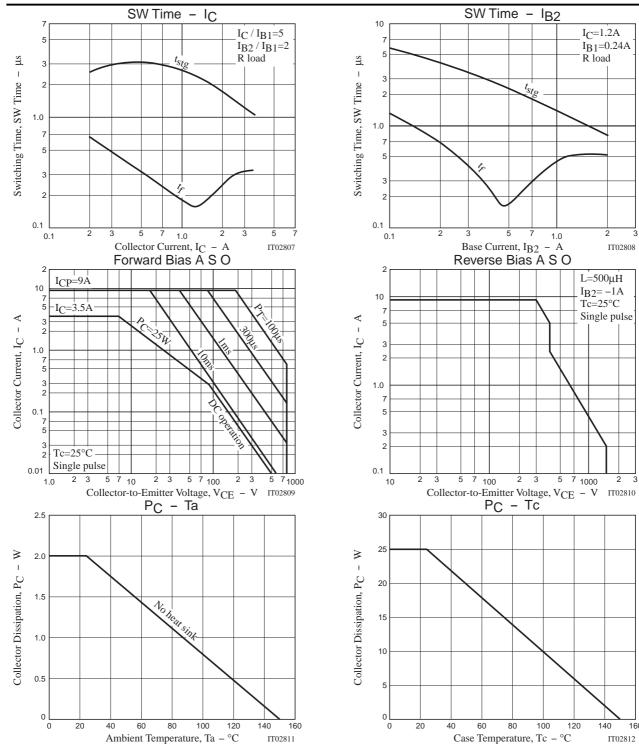
| Parameter                               | Symbol                | Conditions                              | Ratings |     |     | Unit |
|---|-----------------------|---|---------|-----|-----|------|
|   |                       |   | min     | typ | max | Onit |
| Collector-to-Emitter Saturation Voltage | V <sub>CE</sub> (sat) | IC=1.8A, IB=0.36A                       |         |     | 3   | V    |
| Base-to-Emitter Saturation Voltage      | V <sub>BE</sub> (sat) | IC=1.8A, IB=0.36A                       |         |     | 1.5 | V    |
| DC Current Gain                         | hFE1                  | VCE=5V, IC=0.5A                         | 5       |     |     |      |
|   | hFE2                  | V <sub>CE</sub> =5V, I <sub>C</sub> =2A | 5       |     | 8   |      |
| Diode Forward Voltage                   | VF                    | IEC=3A                                  |         |     | 2   | V    |
| Fall Time                               | tf                    | IC=1.2A, IB1=0.24A, IB2=-0.48A          |         |     | 0.3 | μs   |

## **Switching Time Test Circuit**





No.7214-2/4



 $I_C=1.2A$ 

tstg

5

1.0

100

120

140

160

IT02812

80

I<sub>B1</sub>=0.24A R load

2

L=500µH

 $I_{B2} = -1A$ Tc=25°C

Single pulse

3

IT02808

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